DataSheet

1 General Description

The AS5215 is a redundant, contactless rotary encoder sensor for accurate angular measurement over a full turn of 360° and over an extended ambient temperature range of -40°C to +150°C.

Based on an integrated Hall element array, the angular position of a simple two-pole magnet is translated into analog output voltages. The angle information is provided by means of buffered sine and cosine voltages. This approach gives maximum flexibility in system design, as it can be directly integrated into existing architectures and optimized for various applications in terms of speed and accuracy.

With two independent dies in one package, the device offers true redundancy. Usually the bottom die, which is exposed to slightly less magnetic field is employed for plausibility check.

An SSI Interface is implemented for signal path configuration as well as a one time programmable register block (OTP), which allows the customer to adjust the signal path gain to adjust for different mechanical constraints and magnetic field.

2 Key Features

- Contactless angular position encoding
- High precision analog output
- Buffered Sine and Cosine signals
- SSI Interface
- Low power mode
- Two programmable output modes: Differential or Single ended

22 austria**micro**systems

a leap ahead in analog

- Wide magnetic field input range: 20 80 mT
- Wide temperature range: -40°C to +150°C
- Fully automotive qualified to AEC-Q100, grade 0
- Thin punched 32-pin QFN (7x7mm) package

3 Applications

The AS5215 is ideal for Electronic Power Steering systems and general purpose for automotive or industrial applications in microcontroller-based systems.

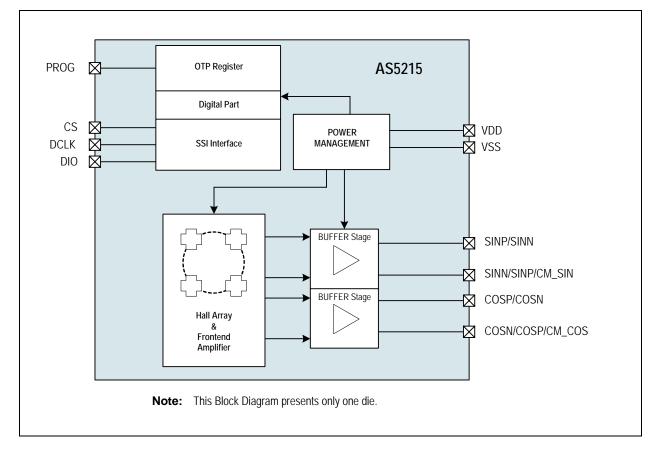


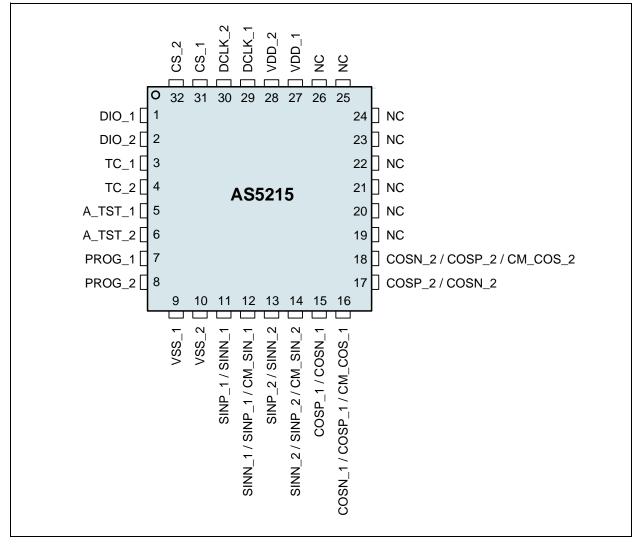
Figure 1. AS5215 Block Diagram

Contents

1 General Description		1
2 Key Features		1
3 Applications		1
4 Pin Assignments		3
4.1 Pin Description	S	3
5 Absolute Maximum I	Ratings	5
	stics	6
	eristics	7
-	er and Vertical Distance	
7.1.1 The Line	ear Range	8
	Thickness	
7.1.3 Axial Dis	stance (Airgap)	12
7.1.4 Angle E	rror vs. Radial and Axial Misalignment	12
7.1.5 Mountin	g the Magnet	12
7.1.6 Summa	ry	14
8 Application Informati	ion	15
8.1 Sleep Mode		15
8.2 SSI Interface		15
8.3 Device Commu	nication / Programming	16
8.4 Waveform – Dig	gital Interface at Normal Operation Mode	18
8.5 Waveform – Dig	gital Interface at Extended Mode	18
8.6 Waveform – Dig	gital Interface at Analog Readback of the Zener Diodes	19
8.7 EasyZapp OTP	Content	19
8.8 Analog Sin/Cos	Outputs with External Interpolator	20
8.9 OTP Programm	ning	21
9 Package Drawings a	and Markings	22
10 Ordering Information	חו	24

4 Pin Assignments

Figure 2. Pin Assignments (Top View)



4.1 Pin Descriptions

Table 1. Pin Descriptions

Pin Name	Pin Number	Description
DIO_1	1	Data I/O for digital interface
DIO_2	2	
TC_1	3	Test coil
TC_2	4	
A_TST_1	5	Analog test pin
A_TST_2	6	
PROG_1	7	OTP Programming Pad
PROG_2	8	UTE Elogianining Eau

Table 1. Pin Descriptions

Pin Name	Pin Number	Description
VSS_1	9	- Supply ground
VSS_2	10	
SINP_1 / SINN_1	11	Switchable buffered analog output
SINN_1 / SINP_1 / CM_SIN_1	12	Switchable buffered analog or common mode output
SINP_2 / SINN_2	13	Switchable buffered analog output
SINN_2 / SINP_2 / CM_SIN_2	14	Switchable buffered analog or common mode output
COSP_1 / COSN_1	15	Switchable buffered analog output
COSN_1/COSP_1/CM_COS_1	16	Switchable buffered analog or common mode output
COSP_2/COSN_2	17	Switchable buffered analog output
COSN_2/COSP_2/CM_COS_2	18	Switchable buffered analog or common mode output
NC	19	
NC	20	
NC	21	
NC	22	
NC	23	
NC	24	
NC	25	_
NC	26	
VDD_1	27	
VDD_2	28	Digital + analog supply
DCLK_1	29	Clock input for digital interface
DCLK_2	30	
CS_1	31	Cleak input for digital interface
CS_2	32	Clock input for digital interface

5 Absolute Maximum Ratings

Stresses beyond those listed in Table 2 may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in Electrical Characteristics on page 6 is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Tahle 2	Ahsolute	Maximum	Ratinas
TUDIC Z.	Absolute	παλιπαπ	Naungs

Parameter	Min	Max	Units	Comments
Supply voltage (VDD)	-0.3	7	V	
Input pin voltage (V_in)	Vss - 0.5	7	V	
Input current (latchup immunity), I_scr	-100	100	mA	Norm: EIA/JESD78 Class II Level A
Electrostatic discharge (ESD)		±2	kV	Norm: JESD22-A114E
Total power dissipation (P _{tot})		275	mW	
Package thermal resistance (Θ_JA)		27	°C/W	Velocity =0; Multi Layer PCB; Jedec Standard Testboard
Storage temperature (T_strg)	-65	150	°C	
Package body temperature (T_body)		260	°C	Norm: IPC/JEDEC J-STD-020C. The reflow peak soldering temperature (body temperature) specified is in accordance with IPC/JEDEC J-STD-020C "Moisture/Reflow Sensitivity Classification for Non- Hermetic Solid State Surface Mount Devices". The lead finish for Pb-free leaded packages is matte tin (100% Sn).
Humidity non-condensing	5	85	%	MSL = 3

6 Electrical Characteristics

Unless otherwise noted all in this specification defined tolerances of parameters are assured over the whole operation conditions range and also over lifetime.

Table 3. Operating Conditions

Symbol	Parameter	Condition	Min	Тур	Max	Unit
Vdd	Positive Supply Voltage		4.5		5.5	V
Vss	Negative Supply Voltage		0.0		0.0	V
T_amb	Ambient temperature		-40		150	٥C

Table 4. DC/AC Characteristics for Digital Inputs and Outputs

Symbol	Parameter	Condition	Min	Тур	Max	Unit
CMOS Inp	ut					
V_IH	High level Input voltage		0.7 * Vdd		Vdd + 0.5	V
V_IL	Low level Input Voltage		Vdd - 0.5		VDD + 0.5	V
I_LEAK	Input Leakage Current				1	μA
CMOS Out	CMOS Output					
V_OH	High level Output voltage	4 mA	Vdd - 0.5			V
V_OL	Low level Output Voltage	4 mA			Vss + 0.4	V
C_L	Capacitive Load				35	pF
t_slew	Slew Rate				30	ns
t_delay	Time Rise Fall				15	ns
CMOS Out	put Tristate					
I_OZ	Tristate Leakage Current				1	μA

Table 5. Magnetic Input Specification

Symbol	Parameter	Condition		Тур	Max	Unit
Two pole cylindrical magnet, diametrically magnetized:						
d _{MAG}	Diameter		4	6		mm
B _{pp}	Magnetic input field amplitude	200 – 800 Gauss	20	50	80	mt
f _{rot}	Rotational speed	Max 30000 RPM	0		500	Hz

Table 6. Electrical System Specifications

Symbol	Parameter	Condition	Min	Тур	Max	Unit
IDD	Current Consumption	Max value derived at maximum I_H (Hall Bias Current)	20		28	mA
		Note: For single die only.				
t _{power_on}	Power up time				1.275	ms
tprop	Propagation delay	-40 to 150°C	18	22	30	μs
М	Magnetic Sensitivity	1G = 0.1 mT	1		6	mV/G
Vout	Analog output range		Vss+ 0.25		Vdd- 0.5	V

Table 6. Electrical System Specifications

Symbol	Parameter	Condition	Min	Тур	Max	Unit
SF=SF _{25C} - ₍ AP1_1/ AP2_1)	Amplitude ratio tracking accuracy over temperature	-40 to 150°C	-1		+1	%
SF=AP1_ 1/AP2_1	Amplitude ratio mismatch at room temperature		-2		2	%
Voffset1	DC Offset	Ratiometric to Vpp	0.294	0.3	0.306	V / Vdd
V _{offset2}	DC Olisei	Rationetric to VDD	0.49	0.5	0.51	V / Vdd
DCoffdrift	DC Offset Drift	-40 to 150°C	-50		+50	µV/⁰C
THD	Total Harmonic Distortion				0.2	%
SR	Slew Rate			1		V/µs
Cload	Capacitive Load				1000	pF

6.1 Timing Characteristics

Table 7. Timing Characteristics

Symbol	Parameter	Condition	Min	Тур	Max	Unit
t1_3	Chip select to positive edge of DCLK		30		-	ns
t2_3	Chip select to drive bus externally		0		-	ns
t3	Setup time command bit Data valid to positive edge of DCLK		30		-	ns
t4	Hold time command bit Data valid after positive edge of DCLK		15		-	ns
t5	Float time Positive edge of DCLK for last command bit to bus float		-		DCLK/ 2+0	ns
t6	Bus driving time Positive edge of DCLK for last command bit to bus drive		DCLK/ 2+0		-	ns
t7	Data valid time Positive edge of DCLK to bus valid		DCLK/ 2+0		DCLK/ 2+30	ns
t8	Hold time data bit Data valid after positive edge of DCLK		DCLK/ 2+0		-	ns
t9_3	Hold time chip select Positive edge DCLK to negative edge of chip select		DCLK/ 2+0		-	ns
t10_3	Bus floating time Negative edge of chip select to float bus		-		30	ns
t11	Setup time data bit at write access Data valid to positive edge of DCLK		30		-	ns
t12	Hold time data bit at write access Data valid after positive edge of DCLK		15		-	ns
t13_3	Bus floating time Negative edge of chip select to float bus		-		30	ns

Remark: The digital interface will be reset during the low phase of the CS signal.

7 Detailed Description

The AS5215 is a redundant rotary encoder sensor front end. Based on an integrated Hall element array, the angular position of a simple two-pole magnet is translated into analog output voltages. The angle information is provided by means of sine and cosine voltages. This approach gives maximum flexibility in system design, as it can be directly integrated into existing architectures and optimized for various applications in terms of speed and accuracy.

With two independent dies in one package, the device offers true redundancy. Usually the bottom die, which is exposed to slightly less magnetic field is employed for plausibility check.

An SSI (SPI standard) protocol is implemented for internal test access to the different circuit blocks and for signal path configuration.

A One Time Programmable register block (OTP) allows the customer to adjust the signal path gain to adjust for different mechanical constraints and magnetic field strengths. Furthermore, for internal use, the test mode can be enabled and the system oscillator is trimmable, DC offset of the output signal can be set to either 1.5V or 2.5V. A unique chip ID is stored to ensure traceability.

For operating point control, a band gap circuit is implemented together with a central bias block to distribute all reference bias currents for the analog signal conditioning. The digital signal part is based on a 2MHz system, CLK derived via. divider from a 4MHz system oscillator.



Figure 3. Typical Arrangement of AS5215 and Magnet

7.1 Magnet Diameter and Vertical Distance

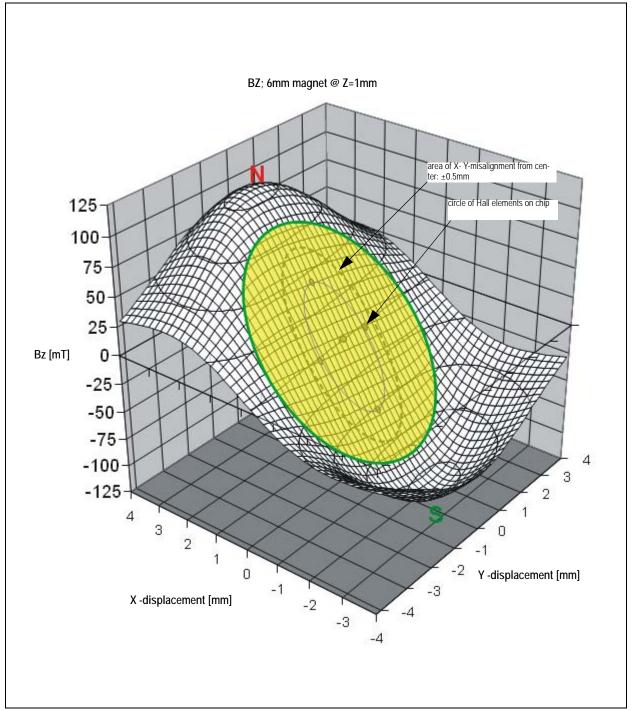
Note: Following is just an abstract taken from the elaborate application note on the Magnet. For more detailed information, please visit our homepage www.austriamicrosystems.com → Magnetic Rotary Encoders → Magnet Application Notes

7.1.1 The Linear Range

The Hall elements used in the AS5000-series sensor ICs are sensitive to the magnetic field component Bz, which is the magnetic field vertical to the chip surface. Figure 4 shows a 3-dimensional graph of the Bz field across the surface of a 6mm diameter, cylindrical NdFeB N35H magnet at an axial distance of 1mm between magnet and IC.

The highest magnetic field occurs at the north and south poles, which are located close to the edge of the magnet, at ~2.8mm radius (see Figure 5). Following the poles towards the center of the magnet, the Bz field decreases very linearly within a radius of ~1.6mm. This linear range is the operating range of the magnet with respect to the Hall sensor array on the chip. For best performance, the Hall elements should always be within this linear range.

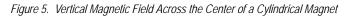


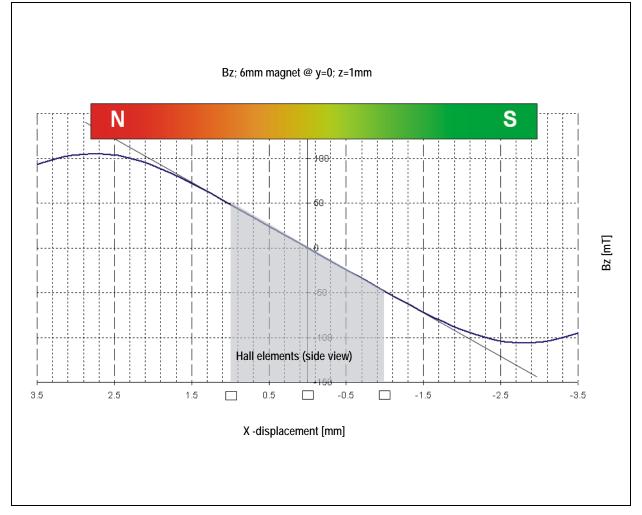


As shown in Figure 5 (grey zone), the Hall elements are located on the chip at a circle with a radius of 1mm. Since the difference between two opposite Hall sensors is measured, there will be no difference in signal amplitude when the magnet is perfectly centered or if the magnet is misaligned in any direction as long as all Hall elements stay within the linear range.

For the 6mm magnet (shown in Figure 5), the linear range has a radius of 1.6mm, hence this magnet allows a radial misalignment of 0.5mm (1.6mm linear range radius; 1mm Hall array radius). Consequently, the larger the linear range, the more radial misalignment can be tolerated. By contrast, the slope of the linear range decreases with increasing magnet diameter, as the poles are further apart. A smaller slope results in a smaller differential signal, which means that the magnet must be moved closer to the IC (smaller airgap) or the amplification gain must be increased, which leads to a poorer signal-to-noise ratio. More noise results in more jitter at the angle output. A good compromise is a magnet diameter in the range of 5...8mm.

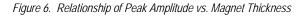
Small Diameter Magnet (<6mm)	Large Diameter Magnet (>6mm)
+ stronger differential signal = good signal / noise ratio, larger airgaps	+ wider linear range = larger horizontal misalignment area
- shorter linear range = smaller horizontal misalignment area	- weaker differential signal = poorer signal / noise ratio, smaller airgaps

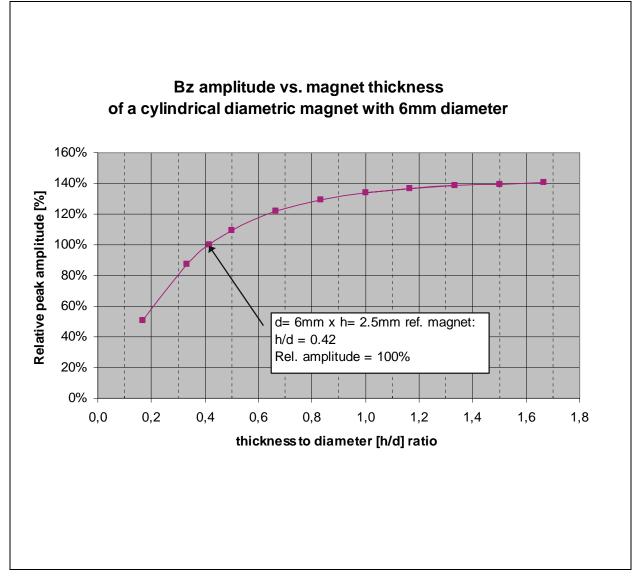




7.1.2 Magnet Thickness

Figure 6 shows the relationship of the peak amplitude in a rotating system (essentially the magnetic field strength of the Bz field component) in relation to the thickness of the magnet. The X-axis shows the ratio of magnet thickness (or height) [h] to magnet diameter [d] and the Y-axis shows the relative peak amplitude with reference to the recommended magnet (d=6mm, h=2.5mm). This results in an h/d ratio of 0.42.



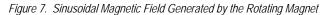


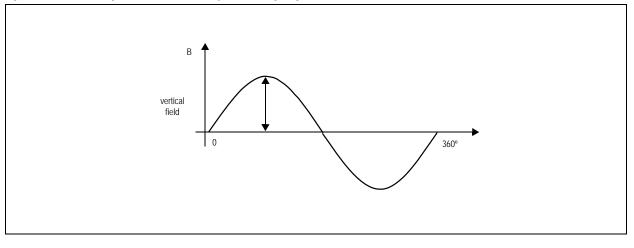
As the graph in Figure 6 shows, the amplitude drops significantly at h/d ratios below this value and remains relatively flat at ratios above 1.3.

Therefore, the recommended thickness of 2.5mm (at 6mm diameter) should be considered as the low limit with regards to magnet thickness.

It is possible to get 40% or more signal amplitude by using thicker magnets. However, the gain in signal amplitude becomes less significant for h/ d ratios >~1.3. Therefore, the recommended magnet thickness for a 6mm diameter magnet is between 2.5 and ~8 mm.

7.1.3 Axial Distance (Airgap)





The recommended magnetic field, measured at the chip surface on a radius equal to the Hall sensor array radius (typ 1mm) should be within a certain range. This range lies between 45 and 75mT or between 20 and 80mT, depending on the encoder product.

Linear position sensors are more sensitive as they use weaker magnets. The allowed magnetic range lies typically between 5 and 60mT.

7.1.4 Angle Error vs. Radial and Axial Misalignment

The angle error is the deviation of the actual angle vs. the angle measured by the encoder. There are several factors in the chip itself that contribute to this error, mainly offset and gain matching of the amplifiers in the analog signal path. On the other hand, there is the nonlinearity of the signals coming from the Hall sensors, caused by misalignment of the magnet and imperfections in the magnetic material.

Ideally, the Hall sensor signals should be sinusoidal, with equal peak amplitude of each signal. This can be maintained, as long as all Hall elements are within the linear range of the magnetic field Bz (see Figure 5).

7.1.5 Mounting the Magnet

Generally, for on-axis rotation angle measurement, the magnet must be mounted centered over the IC package. However, the material of the shaft into which the magnet is mounted, is also of big importance.

Magnetic materials in the vicinity of the magnet will distort or weaken the magnetic field being picked up by the Hall elements and cause additional errors in the angular output of the sensor.

Figure 8. Magnetic Field Lines in Air

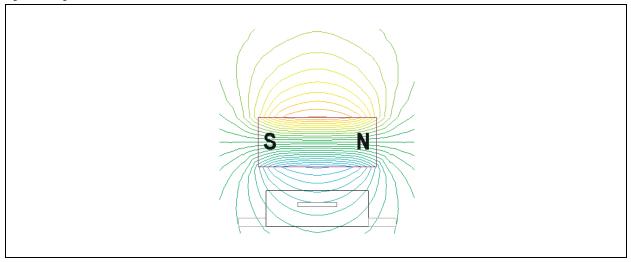
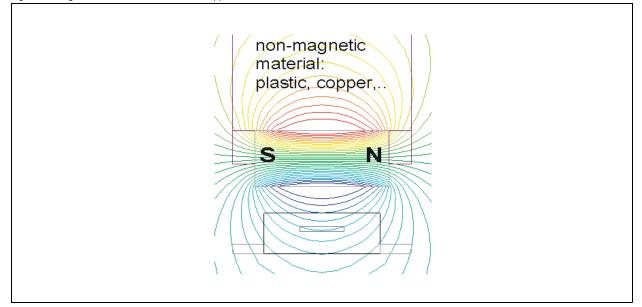


Figure 8 shows the ideal case with the magnet in air. No magnetic materials are anywhere nearby.

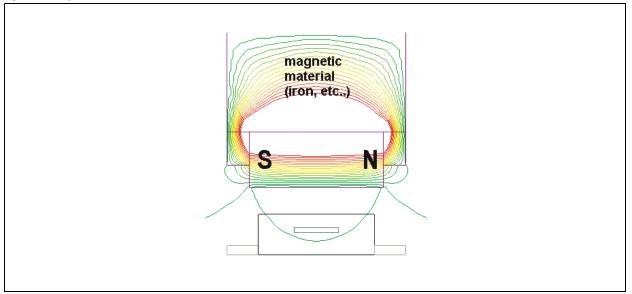
Figure 9. Magnetic Field Lines in Plastic or Copper Shaft



If the magnet is mounted in non-magnetic material, such as plastic or diamagnetic material, such as copper, the magnetic field distribution is not disturbed. Even paramagnetic material, such as aluminium may be used. The magnet may be mounted directly in the shaft (see Figure 9).

Note: Stainless steel may also be used, but some grades are magnetic. Therefore, steel with magnetic grades should be avoided.

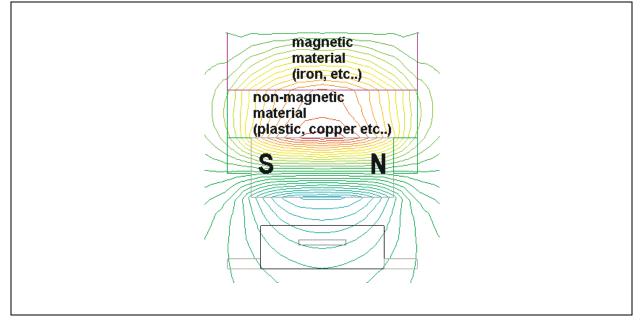




If the magnet is mounted in a ferromagnetic material, such as iron, most of the field lines are attracted by the iron and flow inside the metal shaft (see Figure 10). The magnet is weakened substantially.

This configuration should be avoided!





If the magnet has to be mounted inside a magnetic shaft, a possible solution is to place a non-magnetic spacer between shaft and magnet, as shown in Figure 11. While the magnetic field is rather distorted towards the shaft, there are still adequate field lines available towards the sensor IC. The distortion remains reasonably low.

7.1.6 Summary

- Small diameter magnets (<6mm Ø) have a shorter linear range and allow less lateral misalignment. The steeper slope allows larger axial distances.
- Large diameter magnets (>6 mm Ø) have a wider linear range and allow a wider lateral misalignment. The flatter slope requires shorter axial distances.
- The linear range decreases with airgap; Best performance is achieved at shorter airgaps.
- The ideal vertical distance range can be determined by using magnetic range indicators provided by the encoder ICs. These indicators are named MagInc, MagDec, MagRngn, or similar, depending on product.

8 Application Information

8.1 Sleep Mode

The target is to provide the possibility to reduce the total current consumption. No output signal will be provided when the IC is in sleep mode. Enabling or disabling sleep mode is done by sending the SLEEP or WAKEUP commands via. the SSI interface. Analog blocks are powered down with respect to fast wake up time.

8.2 SSI Interface

The setup for the device is handled by the digital interface. Each communication starts with the rising edge of the chip select signal. The synchronization between the internal free running analog clock oscillator and the external used digital clock source for the digital interface is done in a way that the digital clock frequency can vary in a wide range.

Table 8. SSI Interface Pin Description	ole 8. S	SI Interface	e Pin Descriptio
--	----------	--------------	------------------

Port	Symbol	Function
Chip select	CS	Indicates the start of a new access cycle to the device $CS = LO \rightarrow$ reset of the digital interface
DCLK	DCLK	Clock source for the communication over the digital interface
Bidirectional data input output	DIO	Command and data information over one single line The first bit of the command defines a read or write access

Table 9. SSI Interface Parameter Description

Symbol	Parameter	Notes	Min	Тур	Мах	Unit					
f_DCLK	Clock frequency at normal operation	The nominal value for the clock frequency can	no limit	5	6	MHz					
f_EZ_RW	Clock frequency at easy zap read write access	be derived from a 10MHz oscillator source.	no limit	5	6	kHz					
f_EZ_PR OG	Clock frequency at easy zap access program OTP	Correct access to the programmable zener diode block needs a strict timing – the zap pulse is exact one period. The nominal value for the clock frequency can be derived from a 10MHz oscillator source.	200	-	650	kHz					
f_EZ_AR	Clock frequency at easy zap analog	20pF external load allowed.									
B	readback	The nominal value for the clock frequency can be derived from a 10MHz oscillator source.	no limit	156.3	162.5	kHz					
Interface C	General at normal mode										
Protocol: 5	command bit + 16 data input output										
Command		5 bit command: cmd<4:0> \leftarrow bit<21:16>									
Data		16 bit data: data<15:0> ← bit<15:0>									
Interface C	General at extended mode										
Protocol: 5	command bit + 46 data input output										
Command		5 bit command: cmd<4:0> \leftarrow bit<50:46>									
Data		34 bit data: data<45:0> ← bit<45:0>									
Interface N	lodes										
Normal rea	d operation mode	$cmd<4:0> = <00xxx> \rightarrow 1 DCLK per data bit$									
Extended r	ead operation mode	$cmd<4:0> = <01xxx> \rightarrow 4 DCLK per data bit$									
Normal write	e operation mode	$cmd<4:0> = <10xxx> \rightarrow 1 DCLK per data bit$									
Extended v	rite operation mode	$cmd<4:0> = <11xxx> \rightarrow 4 DCLK per data bit$									

8.3 Device Communication / Programming

Table 10. Digital Interface at Normal Mode

#	command	bin	mode	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
23	WRITE CONFIG 1	10111	write	go2sleep	gen_rst					analog_sig	OB_bypassed								
16	EN_PROG	10000	write	1	0	0	0	1	1	0	0	1	0	1	0	1	1	1	0

Name	Functionality
go2sleep	Enter/leave low power mode (no output signals)
gen_rst	Generates global reset
analog_sig	Switches the channels to the test bus after the PGA
OB_bypassed	Disable and bypass output buffer for testing purpose

Table 11. Digital Interface at Extended Mode

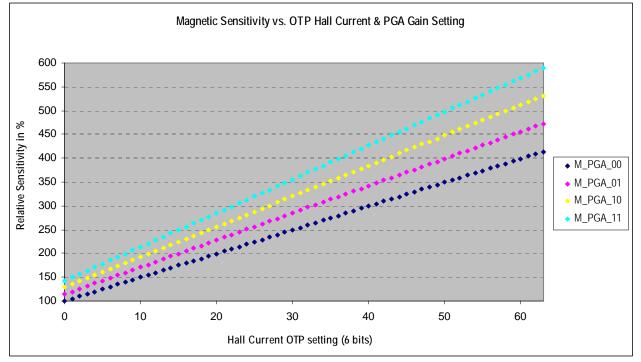
						Fac	tory Set	tings				User Settings						
#	command	bin	mode	<45:44>	<43: 26>	<25:23>	<22:2 0>	<19:1 8>	<17:1 4>	<13>	<12>	<11>	<10>	<9>	<8:7>	<6>	<5:0>	
31	WRITE OTP	11111	xt write	otp test	ID	10µbiastrim		vref	OSC	lock_0 TP	n.c.	invert_ channel	cm_sin	cm_cos	gain	dc_ offset	hall_ bias	
25	PROG_OTP	11001	xt write	otp test	ID	10µbiastrim		vref	OSC	lock_O TP	n.c.	invert_ channel	cm_sin	cm_cos	gain	dc_ offset	hall_ bias	
15	RD_OTP	01111	xt read	otp test	ID	10µbiastrim		vref	OSC	lock_O TP	n.c.	invert_ channel	cm_sin	cm_cos	gain	dc_ offset	hall_ bias	
9	RD_OTP_ANA	01001	xt read															

Remark:

- 1. Send EN PROG (command 16) in normal mode before accessing the OTP in extended mode.
- 2. OTP assignment will be defined/updated.

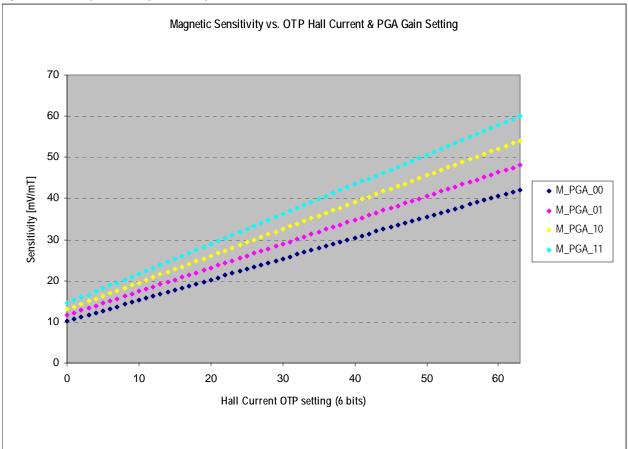
Name	Functionality
Otp_test	Dummy fuse bit used in production test
ID	Part identification
n.c.	Not connected
10µbiastrim	10µ bias current trim bits
vref	Bias Block reference voltage trim bits
OSC	Oscillator trimming bits
lock_OTP	To disable the programming of the factory bits <4514>
invert_channel	Inverts SIN and COS channel before the PGA for inverted output function (0SIN/COS, 1SINN/ COSN)
cm_sin	Common mode voltage output enabled at SINN / CM pin (0differential, 1common)
cm_cos	Common mode voltage output enabled at COSN / CM pin (0differential, 1common)
gain	PGA gain setting (influences overall magnetic sensitivity), 2bit
dc_offset	Output DC offset (01.5V, 12.5V)
Hall_b	Hall bias setting (influences overall magnetic sensitivity), 6bit





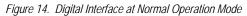
The amplitude of the output signal is programmable via sensitivity (6bit) and/or gain (2bit) settings (see Figure 12).

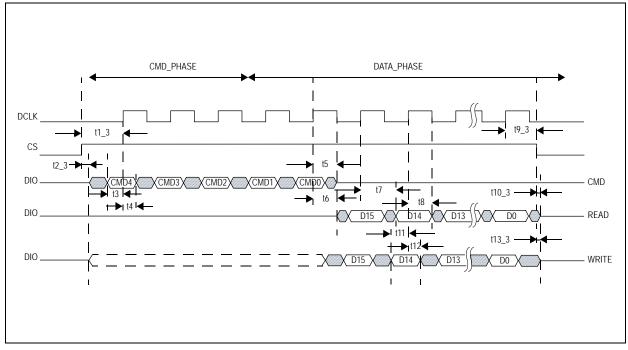
Figure 13. Sensitivity Gain Settings - Sensitivity [mV/mT]



Downloaded from Elcodis.com electronic components distributor

8.4 Waveform – Digital Interface at Normal Operation Mode





8.5 Waveform – Digital Interface at Extended Mode

In the extended mode, the digital interface needs four clocks for one data bit. During this time, the device is able to handle internal signals for special access (e.g. the easy zap interface).

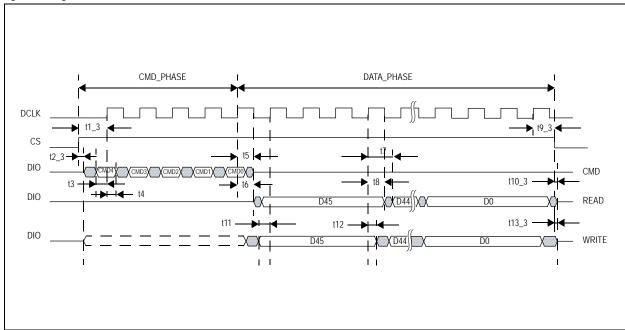
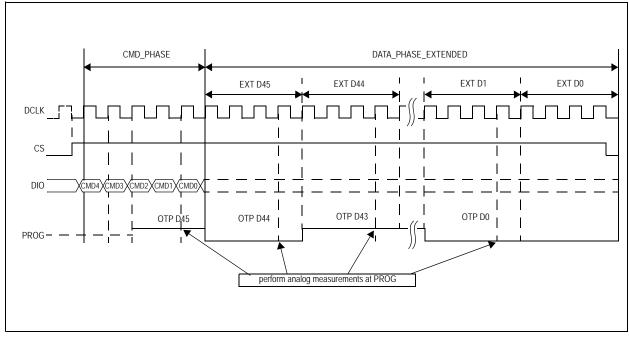


Figure 15. Digital Interface at Extended Mode

8.6 Waveform – Digital Interface at Analog Readback of the Zener Diodes

To be sure that all Zener-Diodes are correctly burned, an analog readback mechanism is defined. Perform the 'READ OTP ANA' sequence according to the command table and measure the value of the diode at the end of each phase.



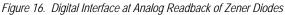


Table 12. Serial Bit Sequence (16-bit read / write)

	Write	e Com	mand								Rea	d / Wri	te Data	1						
C4	C3	C2	C1	C0	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0

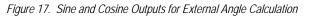
8.7 EasyZapp OTP Content

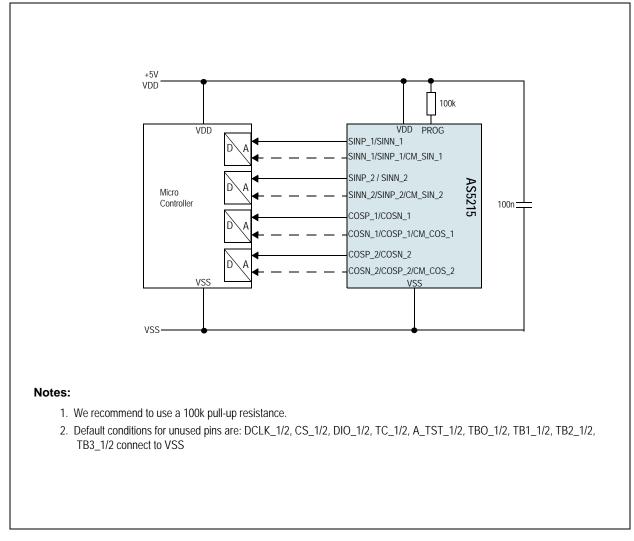
Each AS5215 die has an integrated 32-bit OTP ROM (Easyzapp) for trimming and configuration purposes. The PROM can be programmed via. the serial interface. For irreversible programming, an external programming voltage at PROG pin is needed. For security reasons, the factory trim bits can be locked by a lock bit.

Name	Bit Count	OTP Start	OTP End	Access	Comments
Hall Bias	6	0	5	user	Sets overall sensitivity
DC offset	1	6	6	user	Output DC offset setting
gain	2	7	8	user	Programmable gain amplifier setting
Lock	1	13	13	austriamicrosystems	Set in production test
invert_channel	1	11	11	user	Inverts SIN and COS channel before the PGA for inverted output function
cm_sin	1	10	10	user	Common mode voltage output enabled at SINN / CM pin
cm_cos	1	9	9	user	Common mode voltage output enabled at COSN / CM pin

Remark: OTP assignment will be defined/updated.

8.8 Analog Sin/Cos Outputs with External Interpolator



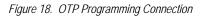


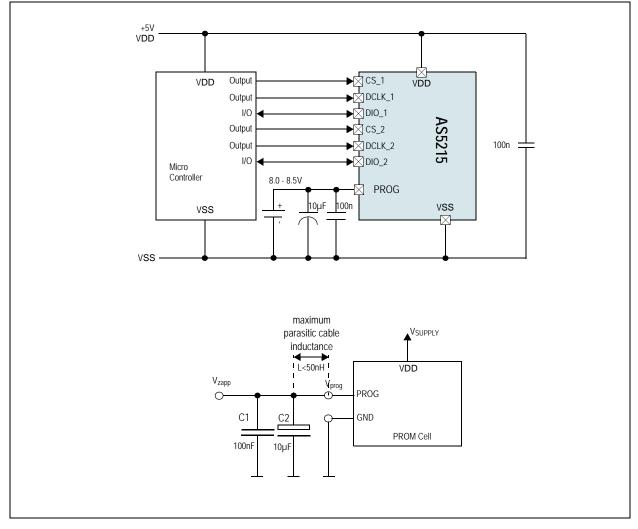
The AS5215 provides analog Sine and Cosine outputs (SINP, COSP) of the Hall array front-end for test purposes. These outputs allow the user to perform the angle calculation by an external ADC + μ C, e.g. to compute the angle with a high resolution. The output driver capability is 1mA. The signal lines should be kept as short as possible, longer lines should be shielded in order to achieve best noise performance.

Through the programming of one bit, you have the possibility to choose between the analog Sine and Cosine outputs (SINP, COSP) and their inverted signals (SINN, COSN). Furthermore, by programming the bits <9:10> you can enable the common mode output signals of SIN and COS.

The DC bias voltage is 1.5 or 2.5 V.

8.9 OTP Programming





For programming of the OTP, an additional voltage has to be applied to the pin PROG. It has to be buffered by a fast 100nF capacitor (ceramic) and a 10µF capacitor. The information to be programmed is set by command 25. The OTP bits 16 until 45 are used for AMS factory trimming and cannot be overwritten.

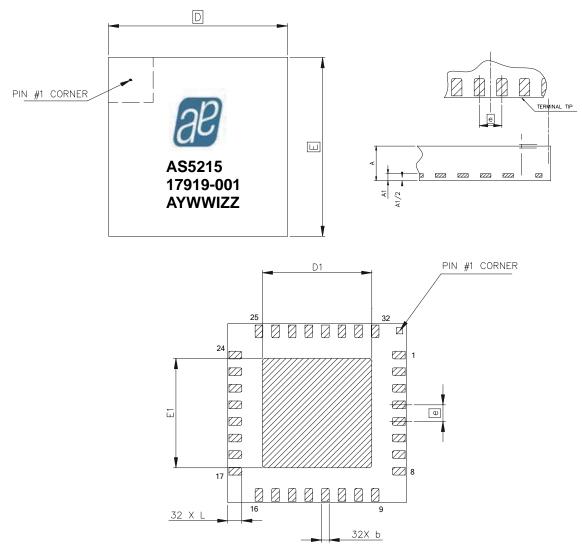
Symbol	Parameter	Min	Max	Unit	Note
Vdd	Supply Voltage	5	5.5	V	
GND	Ground level	0	0	V	
V_zapp	Programming Voltage	8	8.5	V	At pin PROG
T_zapp	Temperature	0	85	°C	
f_clk	CLK Frequency		100	kHz	At pin DCLK

Remark: For normal operation, after programming, apply 100k pull up resistor at PROG pin!

9 Package Drawings and Markings

The devices are available in a 32-pin QFN (7x7mm) package.

Figure 19. 32-pin QFN (7x7mm) Package



Note: The distance between both dies is $150\mu m$.

Symbol		mm			inch				
Symbol	Min	Тур	Мах	Min	Тур	Max			
D		7 BSC		0.28 BSC					
E		7 BSC			0.28 BSC				
D1	4.18	4.28	4.38	0.165	0.169	0.172			
E1	4.18	4.28	4.38	0.165	0.169	0.172			
L	0.45	0.55	0.65	0.018	0.022	0.026			
b	0.25	0.30	0.35	0.010	0.012	0.014			
е		0.65 BSC			0.026 BSC				
А	0.80	0.90	1.00	0.031 0.035 0.039					
A1		0.203 REF			0.008 REF				

Table 13. Package Dimensions



Revision History

Revision	Date	Owner	Description						
1.0	April 29, 2008		Initial revision						
1.0	July 03, 2008		Redundancy Coding topic deleted.						
1.1	July 15, 2008		Updated Key Features, Table 1 - Pin Descriptions, Figure 1 and Figure 17.						
1.2	July 14, 2009		Updated min, typ, max values for 'Power up time' parameter in Table 6.						
1.3	July 31, 2009		 Updated the following parameters in Table 6: Values and conditions updated for 1. Propagation delay 2. Amplitude ratio tracking accuracy over temperature 3. DC Offset Drift Deleted the 'Output Offset' parameter from the table. 						
	Aug 24, 2009	apg	Updated following bits related information on page 16 - invert_channel, cm_sin, cm_cos, gain, dc_offset, Hall_b						
1.4	Aug 26, 2009		Inserted Figure 12 and updated Applications and Figure 17.						
1.5	Sept 01, 2009		Inserted Figure 13, Added a note in Package Drawings and Markings.						
1.6	Sept 02, 2009		Deleted 'Displacement' parameter from Table 5.						
1.7	Nov 26, 2009		Hall Array Radius value updated from 1.1mm to 1mm Updated Figure 13						
1.0	Dec 11, 2009		Updated values for 'Magnetic Sensitivity' parameter in Table 6.						
1.8	Dec 15, 2009		Ordering code updated.						
	Jan 27, 2010								
1.9	Feb 10, 2010								
	Mar 19, 2010		Added 'Current Consumption' parameter in Table 6.						

Note: Typos may not be explicitly mentioned under revision history.

10 Ordering Information

The devices are available as the standard products shown in Table 14.

Table 14. Ordering Information

Ordering Code	Description	Delivery Form	Package
AS5215-HQFT-OM	Sine and cosine analog output magnetic rotary encoder	Tape & Reel	32-pin QFN (7x7mm)

Note: All products are RoHS compliant and Pb-free.

Buy our products or get free samples online at ICdirect: http://www.austriamicrosystems.com/ICdirect

For further information and requests, please contact us mailto:sales@austriamicrosystems.com or find your local distributor at http://www.austriamicrosystems.com/distributor

Copyrights

Copyright © 1997-2010, austriamicrosystems AG, Tobelbaderstrasse 30, 8141 Unterpremstaetten, Austria-Europe. Trademarks Registered ®. All rights reserved. The material herein may not be reproduced, adapted, merged, translated, stored, or used without the prior written consent of the copyright owner.

All products and companies mentioned are trademarks or registered trademarks of their respective companies.

Disclaimer

Devices sold by austriamicrosystems AG are covered by the warranty and patent indemnification provisions appearing in its Term of Sale. austriamicrosystems AG makes no warranty, express, statutory, implied, or by description regarding the information set forth herein or regarding the freedom of the described devices from patent infringement. austriamicrosystems AG reserves the right to change specifications and prices at any time and without notice. Therefore, prior to designing this product into a system, it is necessary to check with austriamicrosystems AG for current information. This product is intended for use in normal commercial applications. Applications requiring extended temperature range, unusual environmental requirements, or high reliability applications, such as military, medical life-support or life-sustaining equipment are specifically not recommended without additional processing by austriamicrosystems AG for each application. For shipments of less than 100 parts the manufacturing flow might show deviations from the standard production flow, such as test flow or test location.

The information furnished here by austriamicrosystems AG is believed to be correct and accurate. However, austriamicrosystems AG shall not be liable to recipient or any third party for any damages, including but not limited to personal injury, property damage, loss of profits, loss of use, interruption of business or indirect, special, incidental or consequential damages, of any kind, in connection with or arising out of the furnishing, performance or use of the technical data herein. No obligation or liability to recipient or any third party shall arise or flow out of austriamicrosystems AG rendering of technical or other services.



Contact Information

Headquarters austriamicrosystems AG Tobelbaderstrasse 30 A-8141 Unterpremstaetten, Austria

Tel: +43 (0) 3136 500 0 Fax: +43 (0) 3136 525 01

For Sales Offices, Distributors and Representatives, please visit:

http://www.austriamicrosystems.com/contact